

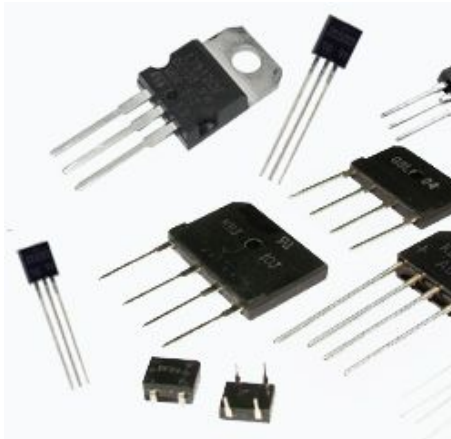


Introduction

Electrical & Electronic Circuits and Elements

Embedded Systems & Embedded Programming

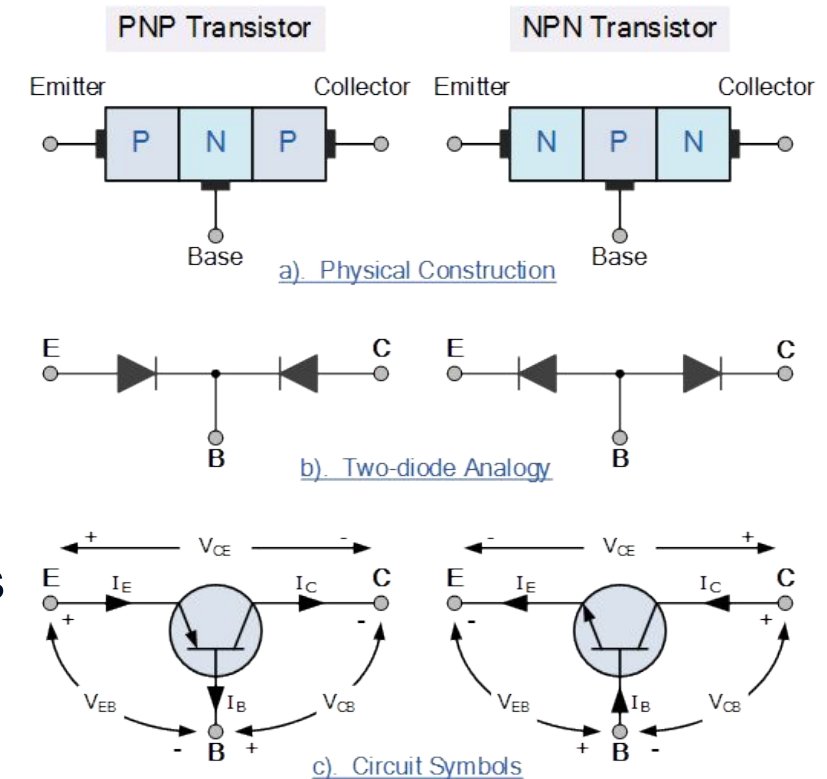
Fundamentals of Electronic Circuits (Transistors)

- ❖ A transistor is an active device that **controls** or **switches** the current flow
 - ❖ Transistor is a combination of two words; **transfer** and **resistor**
 - ❖ They are mainly classified into two types
 - Bipolar Junction Transistor (**BJT**)
 - Field Effect Transistor (**FET**)
 - ❖ They are mainly used
 - As **switches** and signal **amplifiers**
 - In all digital and electronic devices including **ICs**
 - Analog circuits like sensors, RF and etc.
 - ❖ Some IC technologies: **TTL**, **CMOS** and etc.
- 
- A photograph showing a variety of electronic components, including several integrated circuits (ICs) and transistors, scattered on a white background. The components are of different shapes and sizes, with some having multiple pins and others being smaller, discrete components.



Fundamentals of Electronic Circuits (BJT)

- ❖ Bipolar Junction Transistor (**BJT**)
- ❖ Is made by joining together two diodes back-to-back
 - Therefore we have **NPN** and **PNP** types of BJT
- ❖ Both the **electrons** and **holes** are charge carriers
- ❖ Can operate within three different modes:
 - Active (**amplifier**), Saturation (**ON**) and Cutoff (**OFF**)
- ❖ The principle of operation of the **PNP** and **NPN** types is the same and the only difference is biasing and the polarity of the power supply for each type.
- ❖ Was invented by **John Bardeen**, **William Shockley** and **Walter Brattain** in **1948**



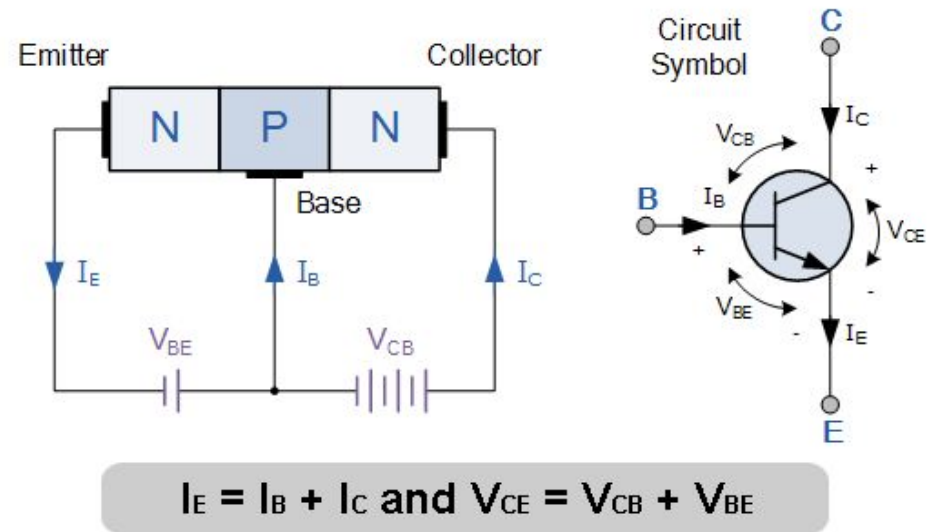
Fundamentals of Electronic Circuits (BJT - NPN)

❖ Cutoff mode

- Both the junctions of the BJT are reverse biased
- No current flows through the device ($I_C = 0$)
- It is in **OFF** state and acts like an **open switch**
- $V_C > V_B < V_E$ ($V_{BE} < 0.7V$ for Silicon)

❖ Saturation mode

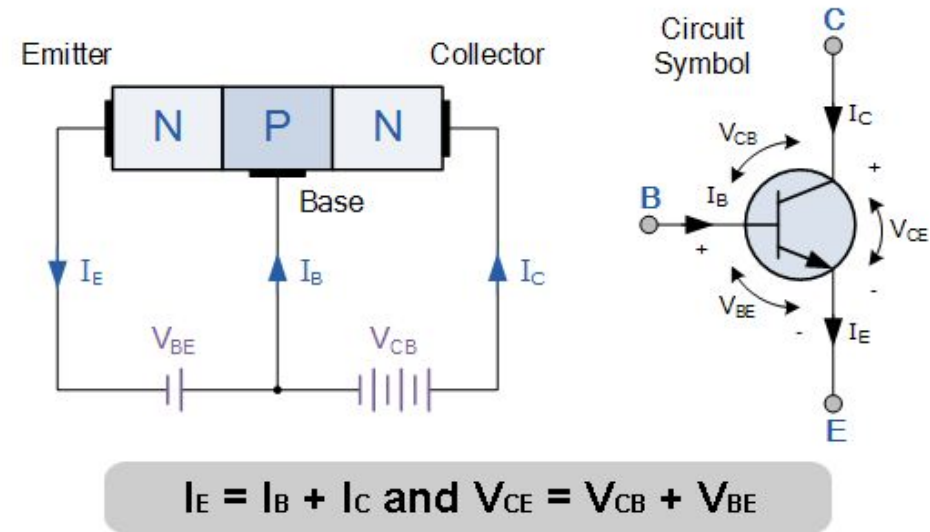
- Both the junctions of the BJT are forward biased
- Huge current flows through the device ($I_C = I_{\text{saturation}}$)
- Increasing I_B doesn't increase I_C ($I_C < \beta * I_B$)
- It is in **ON** state and acts like a **closed switch**
- $V_B > V_C > V_E$ ($V_{BE} > 0.7 V$ for Silicon)
- Collector to emitter saturation voltage $V_{CE(\text{sat})}$ is around 0.05 - 0.2V



Fundamentals of Electronic Circuits (BJT - NPN)

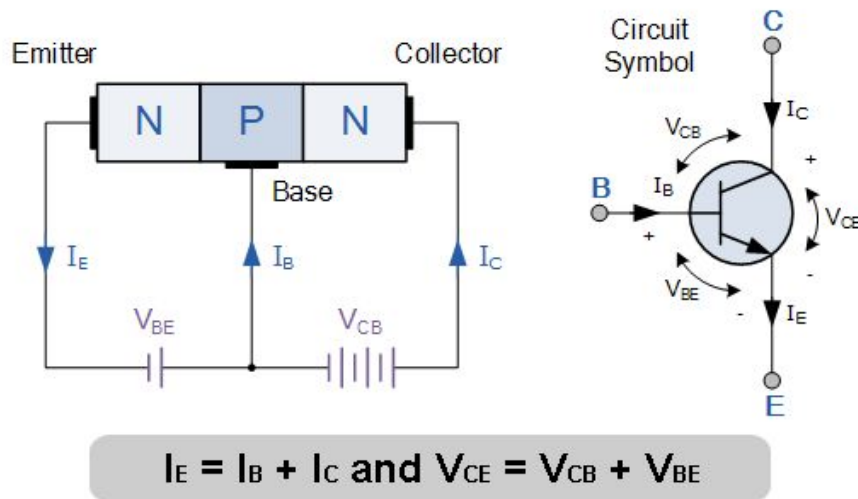
◆ Active mode

- Emitter to base junction is forward biased
- Collector to base junction is reverse biased
- It operates as an **amplifier** and $I_C = \beta * I_B$
- $V_C > V_B > V_E$ ($V_{BE} > 0.7$ V for Silicon)
- β (h_{fe}) is the **DC Current Gain** of the BJT
- β is generally in the range between 50 - 200
- The collector to emitter current gain is called Alpha, $I_C = \alpha * I_E$
- α and β are specified in the datasheet of the device
- $\alpha = \beta / (\beta + 1)$



Fundamentals of Electronic Circuits (BJT - NPN)

❖ i-v characteristic of BJT



[NPN Transistor](#)



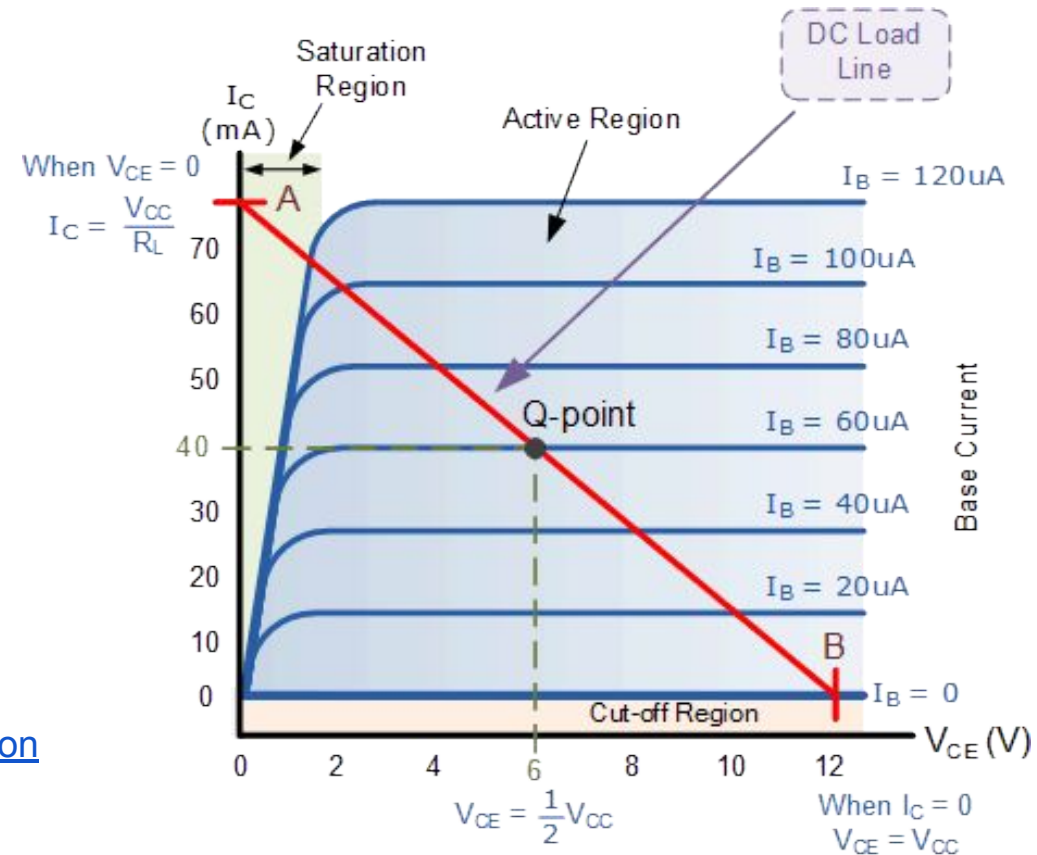
[How does a Transistor Work? A Simple Explanation](#)



[Transistors, How do they work?](#)



[Transistors Explained - How transistors work](#)



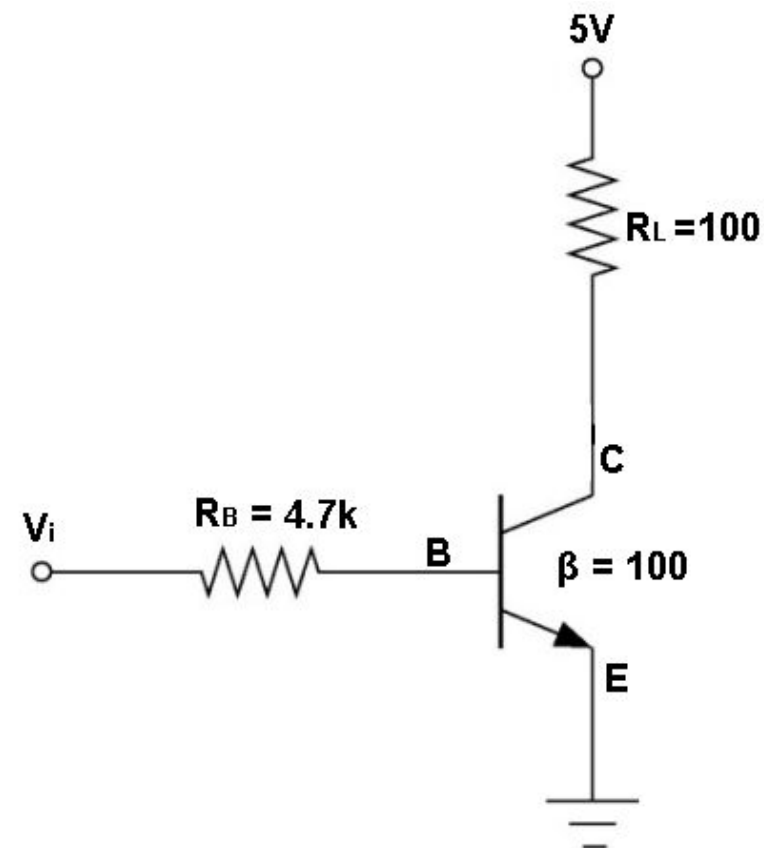
BJT Operating Regions

Fundamentals of Electronic Circuits (BJT - NPN)

- ❖ Find the operation **mode**, **I_B**, **I_C**, **I_E**, **V_{BC}** and **V_{CE}** if
 - $V_i = 0.5 \text{ V}$ (Cutoff, 0 A, 0 A, 0 A, -4.5 V, 5 V)
 - $V_i = 2.0 \text{ V}$ (Active, 0.28 mA, 28 mA, 28.28 mA, -1.5 V, 2.2 V)
 - $V_i = 4.0 \text{ V}$ (Saturation, 0.7 mA, 50 mA, 50.7 mA, 0.7 V, 0 V)
- ❖ Find the minimum V_i and I_B to get the BJT saturated
 - $V_i = 3.05 \text{ V}$
 - $I_B = 0.5 \text{ mA}$

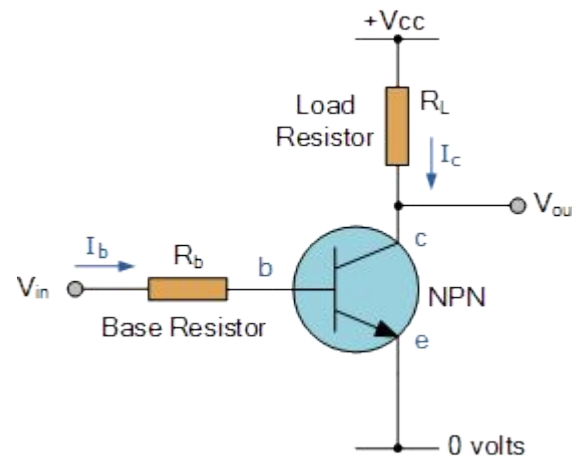
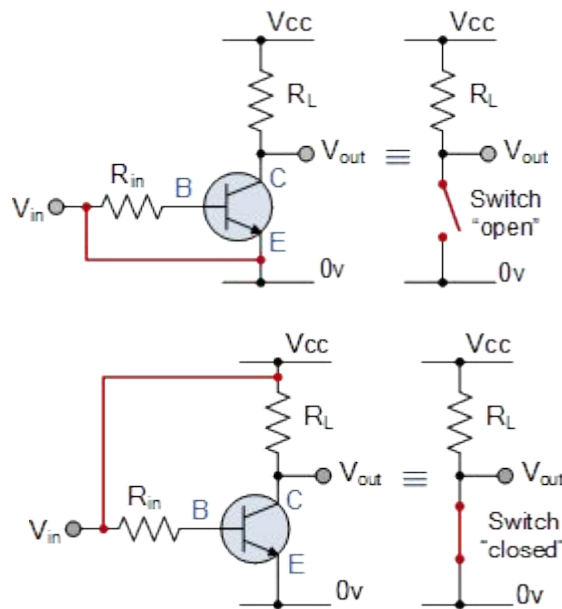
KCL: $I_E = I_B + I_C$

KVL: $V_{CE} = V_{CB} + V_{BE}$



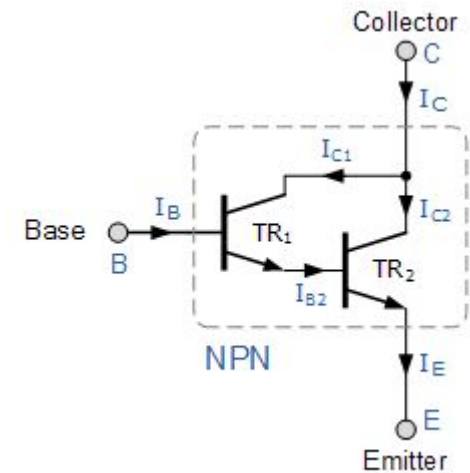
Fundamentals of Electronic Circuits (BJT - NPN)

- ❖ Darlington Transistor (BJT as amplifier)
 - When large currents or voltages need to be controlled
- ❖ BJT as a switch
 - Can be used to switch and control lamps, relays or even motors



[Transistors](#)

[Transistors as a Switch](#)



$$I_c = (\beta_1 + \beta_2 + \beta_1 \cdot \beta_2) \cdot I_B$$

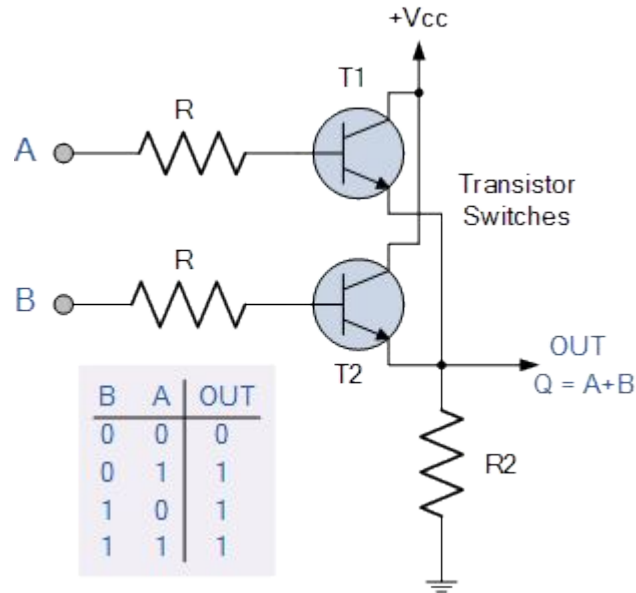
$$\beta = (\beta_1 + \beta_2 + \beta_1 \cdot \beta_2)$$

$V_{BE} > 1.4 \text{ V}$ (for silicon)

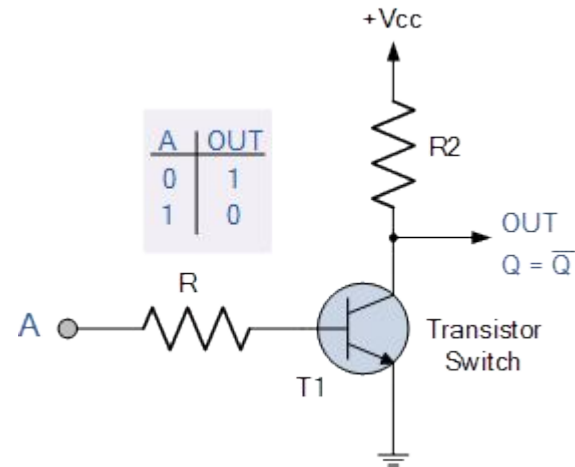
[Transistor as a Switch](#)

Fundamentals of Electronic Circuits (BJT - NPN)

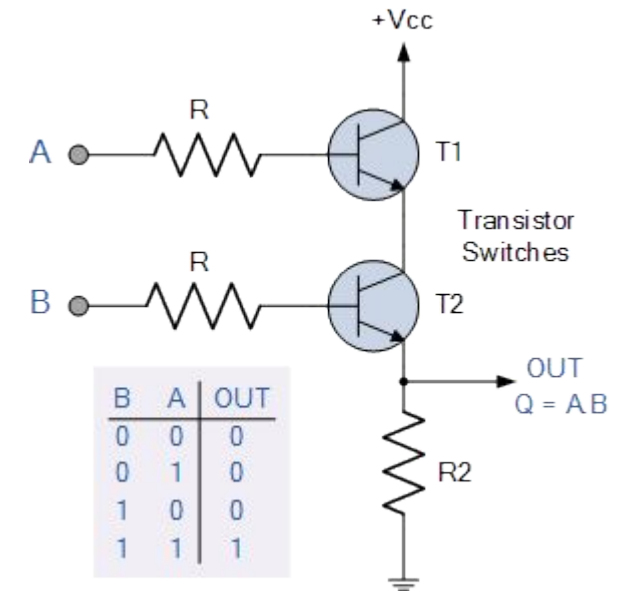
❖ BJTs and Logic Gates



Logic OR Gate



Logic NOT Gate



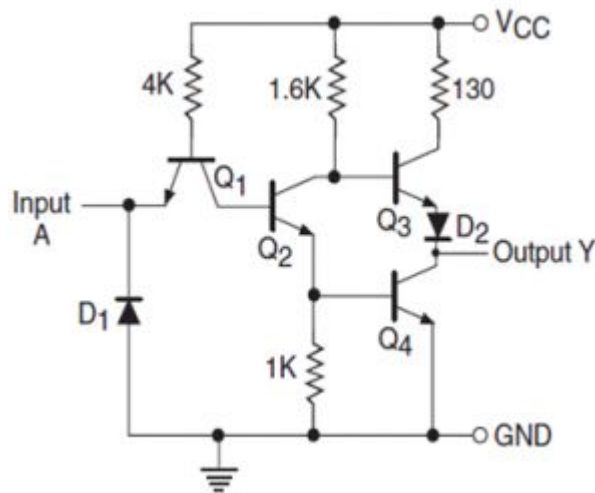
Logic AND Gate



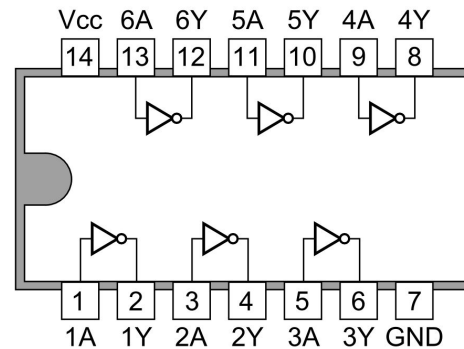
Fundamentals of Electronic Circuits (BJT - NPN)

❖ TTL (Transistor–transistor logic) family

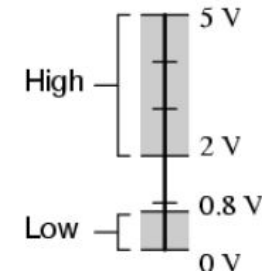
- Is a logic family built from bipolar junction transistors
- Introduced in integrated circuit form in 1963 by Sylvania
- The **7400** series by Texas Instruments became particularly popular



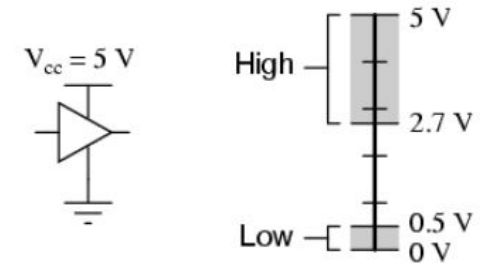
7404 Hex Inverters



Acceptable TTL gate input signal levels



Acceptable TTL gate output signal levels



TTL Inverter (NOT) IC

Fundamentals of Electronic Circuits

❖ Some useful links

- [Bipolar Transistor](#)
- [Bipolar Junction Transistor](#)
- [Introduction to Transistors](#)
- [How to Identify an PNP or NPN Transistor](#)
- [Transistor–Transistor Logic \(TTL\)](#)
- [Emitter-coupled logic](#)
- [The Basics of Emitter-Coupled Logic](#)
- [Emitter-Coupled Logic](#)
- [BJTs as Transistor Switches](#)